

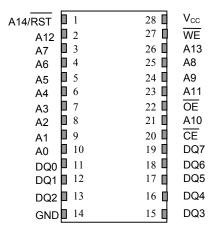
DS1244/DS1244P 256k NV SRAM with Phantom Clock

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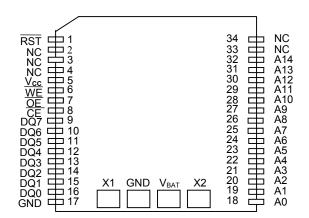
FEATURES

- Real time clock keeps track of hundredths of seconds, minutes, hours, days, date of the month, months, and years
- 32k x 8 NV SRAM directly replaces volatile static RAM or EEPROM
- Embedded lithium energy cell maintains calendar operation and retains RAM data
- Watch function is transparent to RAM operation
- Month and year determine the number of days in each month; valid up to 2100
- Full 10% operating range
- Operating temperature range 0°C to 70°C
- Over 10 years of data retention in the absence of power
- Lithium energy source is electrically disconnected to retain freshness until power is applied for the first time
- DIP Module only
 - Standard 28-pin JEDEC pinout
- PowerCap[®] Module Board only
 - Surface mountable package for direct connection to PowerCap containing battery and crystal
 - Replaceable battery (PowerCap)
 - Pin for pin compatible with DS1248P and DS1251P

PIN ASSIGNMENT



28-Pin Encapsulated Package 740-mil Extended



34-Pin PowerCap Module Board (Uses DS9034PCX PowerCap)

1 of 20 082101

PIN DESCRIPTION ORDERING INFORMATION DS1244YP-XXXY (5V) $A_0 - A_{14}$ Address Inputs - IND Industrial CE - Chip Enable **▶** - 70 70 ns access OE - Output Enable - 100 100 ns access WE - Write Enable 28-pin DIP Module ▶ blank - Power Supply Input V_{CC} 34-pin PowerCap Module P **GND** Ground board* DQ_0-DQ_7 Data In/Data Out DS1244WP-XXXY (3.3V) NC - No Connection - IND Industrial X1,X2 - Crystal Connection 120 ns access **▶** -120 - Battery Connection V_{BAT} 150 ns access -150 RST - Reset 28-pin DIP Module blank 34-pin PowerCap Module board*

DESCRIPTION

The DS1244 256k NV SRAM with Phantom Clock is a fully static nonvolatile RAM (organized as 32k words by 8 bits) with a built–in real time clock. The DS1244 has a self–contained lithium energy source and control circuitry, which constantly monitors V_{CC} for an out–of–tolerance condition. When such a condition occurs, the lithium energy source is automatically switched on and write protection is unconditionally enabled to prevent garbled data in both the memory and real time clock.

The Phantom Clock provides timekeeping information including hundredths of seconds, seconds, minutes, hours, day, date, month, and year information. The date at the end of the month is automatically adjusted for months with less than 31 days, including correction for leap years. The Phantom Clock operates in either 24—hour or 12—hour format with an AM/PM indicator.

PACKAGES

The DS1244 is available in two packages (28–pin DIP and 34–Pin PowerCap module). The 28–pin DIP style module integrates the crystal, lithium energy source, and silicon all in one package. The 34–pin PowerCap Module Board is designed with contacts for connection to a separate PowerCap (DS9034PCX) that contains the crystal and battery. This design allows the PowerCap to be mounted on top of the DS1244P after the completion of the surface mount process. Mounting the PowerCap after the surface mount process prevents damage to the crystal and battery due to the high temperatures required for solder reflow. The PowerCap is keyed to prevent reverse insertion. The PowerCap Module Board and PowerCap are ordered separately and shipped in separate containers. The part number for the Powercap is DS9034PCX.

RAM READ MODE

The DS1244 executes a read cycle whenever WE (Write Enable) is inactive (high) and CE (Chip Enable) is active (low). The unique address specified by the 15 address inputs (A0–A14) defines which of the 32,768 bytes of data is to be accessed. Valid data will be available to the eight data output drivers within t_{ACC} (Access Time) after the last address input signal is stable, providing that \overline{CE} and \overline{OE} (Output Enable) access times and states are also satisfied. If \overline{OE} and \overline{CE} access times are not satisfied, then data access must be measured from the later occurring signal (\overline{CE} or \overline{OE}) and the limiting parameter is either t_{CO} for \overline{CE} or t_{OE} for \overline{OE} rather than address access.

^{*}DS9034PCX (PowerCap) Required: (must be ordered separately)

RAM WRITE MODE

The DS1244 is in the write mode whenever the \overline{WE} and \overline{CE} signals are in the active (low) state after address inputs are stable. The latter occurring falling edge of \overline{CE} or \overline{WE} will determine the start of the write cycle. The write cycle is terminated by the earlier rising edge of \overline{CE} or \overline{WE} . All address inputs must be kept valid throughout the write cycle. \overline{WE} must return to the high state for a minimum recovery time (twr) before another cycle can be initiated. The \overline{OE} control signal should be kept inactive (high) during write cycles to avoid bus contention. However, if the output bus has been enabled (\overline{CE} and \overline{OE} active) then \overline{WE} will disable the outputs in topw from its falling edge.

DATA RETENTION MODE

The 5 volt device is fully accessible and data can be written or read only when V_{CC} is greater than V_{PF} . However, when V_{CC} is below the power fail point, V_{PF} , (point at which write protection occurs) the internal clock registers and SRAM are blocked from any access. When V_{CC} falls below the battery switch point V_{SO} (battery supply level), device power is switched from the V_{CC} pin to the backup battery. RTC operation and SRAM data are maintained from the battery until V_{CC} is returned to nominal levels.

The 3.3 volt device is fully accessible and data can be written or read only when V_{CC} is greater than V_{PF} . When V_{CC} fall as below the power fail point, V_{PF} , access to the device is inhibited. If V_{PF} is less than V_{BAT} , the device power is switched from V_{CC} to the backup supply (V_{BAT}) when V_{CC} drops below V_{PF} . If V_{PF} is greater than V_{BAT} , the device power is switched from V_{CC} to the backup supply (V_{BAT}) when V_{CC} drops below V_{BAT} . RTC operation and SRAM data are maintained from the battery until V_{CC} is returned to nominal levels.

All control, data, and address signals must be powered down when V_{CC} is powered down.

PHANTOM CLOCK OPERATION

Communication with the Phantom Clock is established by pattern recognition on a serial bit stream of 64 bits which must be matched by executing 64 consecutive write cycles containing the proper data on DQ0. All accesses which occur prior to recognition of the 64-bit pattern are directed to memory.

After recognition is established, the next 64 read or write cycles either extract or update data in the Phantom Clock, and memory access is inhibited.

Data transfer to and from the timekeeping function is accomplished with a serial bit stream under control of Chip Enable (CE), Output Enable (OE), and Write Enable (WE). Initially, a read cycle to any memory location using the CE and OE control of the Phantom Clock starts the pattern recognition sequence by moving a pointer to the first bit of the 64-bit comparison register. Next, 64 consecutive write cycles are executed using the CE and WE control of the SmartWatch. These 64 write cycles are used only to gain access to the Phantom Clock. Therefore, any address to the memory in the socket is acceptable. However, the write cycles generated to gain access to the Phantom Clock are also writing data to a location in the mated RAM. The preferred way to manage this requirement is to set aside just one address location in RAM as a Phantom Clock scratch pad. When the first write cycle is executed, it is compared to bit 0 of the 64-bit comparison register. If a match is found, the pointer increments to the next location of the comparison register and awaits the next write cycle. If a match is not found, the pointer does not advance and all subsequent write cycles are ignored. If a read cycle occurs at any time during pattern recognition, the present sequence is aborted and the comparison register pointer is reset. Pattern recognition continues for a total of 64 write cycles as described above until all the bits in the comparison

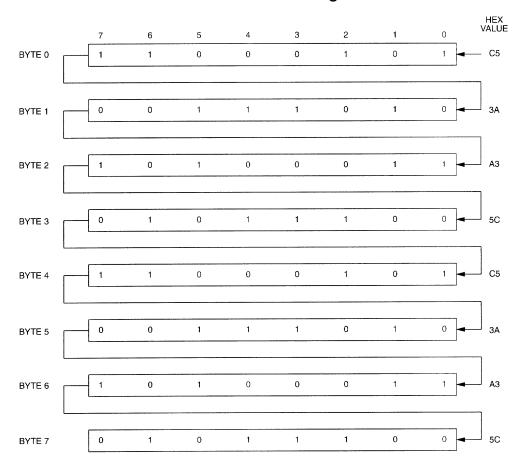
register have been matched (this bit pattern is shown in Figure 1). With a correct match for 64-bits, the Phantom Clock is enabled and data transfer to or from the timekeeping registers can proceed. The next 64 cycles will cause the Phantom Clock to either receive or transmit data on DQ0, depending on the level of the \overline{OE} pin or the \overline{WE} pin. Cycles to other locations outside the memory block can be interleaved with \overline{CE} cycles without interrupting the pattern recognition sequence or data transfer sequence to the Phantom Clock.

PHANTOM CLOCK REGISTER INFORMATION

The Phantom Clock information is contained in eight registers of 8 bits, each of which is sequentially accessed 1 bit at a time after the 64-bit pattern recognition sequence has been completed. When updating the Phantom Clock registers, each register must be handled in groups of 8 bits. Writing and reading individual bits within a register could produce erroneous results. These read/write registers are defined in Figure 2.

Data contained in the Phantom Clock register is in binary coded decimal format (BCD). Reading and writing the registers is always accomplished by stepping through all eight registers, starting with bit 0 of register 0 and ending with bit 7 of register 7.

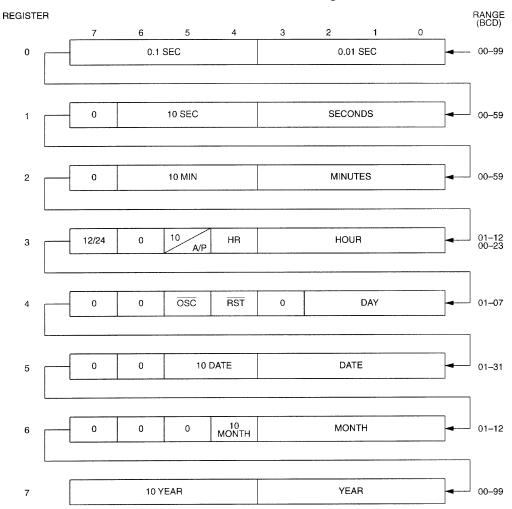
PHANTOM CLOCK REGISTER DEFINITION Figure 1



NOTE:

The pattern recognition in Hex is C5, 3A, A3, 5C, C5, 3A, A3, 5C. The odds of this pattern being accidentally duplicated and causing inadvertent entry to the Phantom Clock is less than 1 in 10¹⁹. This pattern is sent to the Phantom Clock LSB to MSB.

PHANTOM CLOCK REGISTER DEFINITION Figure 2



AM-PM/12/24 MODE

Bit 7 of the hours register is defined as the 12 or 24—hour mode select bit. When high, the 12—hour mode is selected. In the 12—hour mode, bit 5 is the AM/PM bit with logic high being PM. In the 24—hour mode, bit 5 is the second 10—hour bit (20–23 hours).

OSCILLATOR AND RESET BITS

Bits 4 and 5 of the day register are used to control the RESET and oscillator functions. Bit 4 controls the RESET (pin 1). When the RESET bit is set to logic 1, the RESET input pin is ignored. When the RESET bit is set to logic 0, a low input on the RESET pin will cause the Phantom Clock to abort data transfer without changing data in the watch registers. Bit 5 controls the oscillator. When set to logic 1, the oscillator is off. When set to logic 0, the oscillator turns on and the watch becomes operational. These bits are shipped from the factory set to a logic 1.

ZERO BITS

Registers 1, 2, 3, 4, 5, and 6 contain one or more bits which will always read logic 0. When writing these locations, either a logic 1 or 0 is acceptable.

BATTERY LONGEVITY

The DS1244 has a lithium power source that is designed to provide energy for clock activity, and clock and RAM data retention when the V_{CC} supply is not present. The capability of this internal power supply is sufficient to power the DS1244 continuously for the life of the equipment in which it is installed. For specification purposes, the life expectancy is 10 years at 25°C with the internal clock oscillator running in the absence of V_{CC} power. Each DS1244 is shipped from Dallas Semiconductor with its lithium energy source disconnected, guaranteeing full energy capacity. When V_{CC} is first applied at a level greater than V_{PF} , the lithium energy source is enabled for battery backup operation. Actual life expectancy of the DS1244 will be much longer than 10 years since no lithium battery energy is consumed when V_{CC} is present.

CLOCK ACCURACY (DIP MODULE)

The DS1244 is guaranteed to keep time accuracy to within ±1 minute per month at 25°C. The clock is calibrated at the factory by Dallas Semiconductor using special calibration nonvolatile tuning elements and does not require additional calibration. For this reason, methods of field clock calibration are not available and not necessary.

CLOCK ACCURACY (POWERCAP MODULE)

The DS1244P and DS9034PCX are each individually tested for accuracy. Once mounted together, the module will typically keep time accuracy to within ±1.53 minutes per month (35 ppm) at 25°C.

ABSOLUTE MAXIMUM RATINGS*

Voltage on Any Pin Relative to Ground Storage Temperature Soldering Temperature -0.3V to + 6.0V -40°C to +85°C 260°C for 10 seconds (DIP) See Note 13 See IPC/JEDEC Standard J-STD-020A for Surface Mount Devices

OPERATING RANGE

Range	Temperature	V_{CC}
Commercial	0°C to +70°C	$3.3V \pm 10\%$ or $5V \pm 10\%$
Industrial	-40°C to +85°C	$3.3V \pm 10\%$ or $5V \pm 10\%$

^{*} This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

RECOMMENDED DC OPERATING CONDITIONSOver the operating range

PARAMETEI	R	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Innut Logic 1	$V_{CC} = 5V \pm 10\%$	V	2.2		V_{CC} + 0.3 V	V	11
Input Logic 1	V_{CC} =3.3V ± 10%	$ m V_{IH}$	2.0		V _{CC} +0.3V	V	11
Input Logic 0	$V_{CC} = 5V \pm 15\%$	V	-0.3		0.8	V	11
Input Logic 0	V_{CC} =3.3V ± 10%	$ m V_{IL}$	-0.3		0.6	v	11

DC ELECTRICAL CHARACTERISTICSOver the operating range (5V)

	<u> </u>						
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES	
Input Leakage Current	Ι _{IL}	-1.0		+1.0	μΑ	12	
I/O Leakage Current	I IO	-1.0		+1.0	μΑ		
$\overline{\text{CE}} \ge V_{\text{IH}} \le V_{\text{CC}}$							
Output Current @ 2.4V	I_{OH}	-1.0			mA		
Output Current @ 0.4V	I_{OL}	2.0			mA		
Standby Current $\overline{\text{CE}} = 2.2\text{V}$	I_{CCS1}		5	10	mA		
Standby Current $\overline{CE} =$	I _{CCS2}		3.0	5.0	mA		
$V_{\rm CC} - 0.5V$							
Operating Current $t_{CYC} = 70 \text{ ns}$	I _{CC01}			85	mA		
Write Protection Voltage	V_{PF}	4.25	4.37	4.50	V	11	
Battery Switch Over Voltage	V_{SO}		V_{BAT}		V	11	

DC ELECTRICAL CHARACTERISTICS

Over the operating range (3.3V)

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PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Input Leakage Current	Ι _{IL}	-1.0		+1.0	μΑ	12
I/O Leakage Current	I _{IO}	-1.0		+1.0	μΑ	
$\overline{\text{CE}} \ge V_{\text{IH}} \le V_{\text{CC}}$						
Output Current @ 2.4V	I_{OH}	-1.0			mA	
Output Current @ 0.4V	I_{OL}	2.0			mA	
Standby Current $\overline{\text{CE}} = 2.2\text{V}$	I _{CCS1}		5	7	mA	
Standby Current $\overline{CE} =$	I_{CCS2}		2.0	3.0	mA	
$V_{CC} - 0.5V$						
Operating Current $t_{CYC} = 70 \text{ ns}$	I_{CC01}			50	mA	
Write Protection Voltage	V_{PF}	2.80	2.86	2.97	V	11
Battery Switch Over Voltage	V_{SO}		V_{BAT}		V	11
			or			
			$ m V_{PF}$			

CAPACITANCE

 $(t_A = 25^{\circ}C)$

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Input Capacitance	C_{IN}		5	10	pF	
Input/Output Capacitance	C _{I/O}		5	10	pF	

MEMORY AC ELECTRICAL CHARACTERISTICS

Over the operating range (5V)

PARAMETER	SYMBOL	DS124	4Y-70	DS1244			
	STVIDOL	MIN	MAX	MIN	MAX	UNITS	NOTES
Read Cycle Time	t_{RC}	70		100		ns	
Access Time	t_{ACC}		70		100	ns	
OE to Output Valid	t_{OE}		35		55	ns	
CE to Output Valid	t_{CO}		70		100	ns	
OE or CE to Output Active	t _{COE}	5		5		ns	5
Output High Z from Deselection	t_{OD}		25		35	ns	5
Output Hold from Address	t_{OH}	5		5		ns	
Change							
Write Cycle Time	$t_{ m WC}$	70		100		ns	
Write Pulse Width	t_{WP}	50		70		ns	3
Address Setup Time	t_{AW}	0		0		ns	
Write Recovery Time	$t_{ m WR}$	0		0		ns	
Output High Z from WE	t_{ODW}		25		35	ns	5
Output Active from WE	t_{OEW}	5		5		ns	5
Data Setup Time	$t_{ m DS}$	30		40		ns	4
Data Hold Time from WE	t _{DH}	5		5		ns	4

PHANTOM CLOCK AC ELECTRICAL CHARACTERISTICS

Over the operating range (5V)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Read Cycle Time	t_{RC}	65			ns	
CE Access Time	t_{CO}			55	ns	
OE Access Time	t_{OE}			55	ns	
CE to Output Low Z	t_{COE}	5			ns	
OE to Output Low Z	t_{OEE}	5			ns	
CE to Output High Z	t_{OD}			25	ns	5
OE to Output High Z	$t_{\rm ODO}$			25	ns	5
Read Recovery	t_{RR}	10			ns	
Write Cycle Time	$t_{ m WC}$	65			ns	
Write Pulse Width	t_{WP}	55			ns	3
Write Recovery	$t_{ m WR}$	10			ns	10
Data Setup Time	$t_{ m DS}$	30			ns	4
Data Hold Time	$t_{ m DH}$	0			ns	4
CE Pulse Width	t_{CW}	60			ns	
RESET Pulse Width	t_{RST}	65			ns	

POWER-DOWN/POWER-UP TIMING

Over the operating range (5V)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
$\overline{\text{CE}}$ at V_{IH} before Power-Down	t_{PD}	0			μs	
V_{CC} Slew from $V_{PF(max)}$ to	t_{F}	300			μs	
$V_{PF(min)}(\overline{CE} \text{ at } V_{PF})$						
V_{CC} Slew from $V_{PF(min)}$ to V_{SO}	t_{FB}	10			μs	
V_{CC} Slew from $V_{PF(max)}$ to	t_R	0			μs	
$V_{PF(min)}(\overline{CE} \text{ at } V_{PF})$						
$\overline{\text{CE}}$ at V_{IH} after Power-Up	t_{REC}	1.5		2.5	ms	

 $(t_A = 25^{\circ}C)$

					\ -7	1 - 7
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Expected Data Retention Time	$t_{ m DR}$	10			years	9

WARNING:

Under no circumstances are negative undershoots, of any amplitude, allowed when device is in battery backup mode.

MEMORY AC ELECTRICAL CHARACTERISTICS

Over the operating range (3.3V)

		DS124	4W-120				
PARAMETER	SYMBOL	MIN	MAX	MIN	MAX	UNITS	NOTES
Read Cycle Time	t_{RC}	120		150		ns	
Access Time	t_{ACC}		120		150	ns	
OE to Output Valid	t_{OE}		60		75	ns	
CE to Output Valid	t_{CO}		120		150	ns	
OE or CE to Output Active	t_{COE}	5		5		ns	5
Output High Z from Deselection	t_{OD}		40		70	ns	5
Output Hold from Address	t_{OH}	5		5		ns	
Change							
Write Cycle Time	$t_{ m WC}$	120		150		ns	
Write Pulse Width	t_{WP}	90		100		ns	3
Address Setup Time	t_{AW}	0		0		ns	
Write Recovery Time	$t_{ m WR}$	20		20		ns	10
Output High Z from WE	t_{ODW}		40		70	ns	5
Output Active from WE	t_{OEW}	5		5		ns	5
Data Setup Time	$t_{ m DS}$	50		60	-	ns	4
Data Hold Time from WE	t _{DH}	20		20		ns	4

PHANTOM CLOCK AC ELECTRICAL CHARACTERISTICS

Over the operating range (3.3V)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Read Cycle Time	t_{RC}	120			ns	
CE Access Time	t_{CO}			100	ns	
OE Access Time	t_{OE}			100	ns	
CE to Output Low Z	t_{COE}	5			ns	
OE to Output Low Z	$t_{ m OEE}$	5			ns	
CE to Output High Z	t_{OD}			40	ns	5
OE to Output High Z	t_{ODO}			40	ns	5
Read Recovery	t_{RR}	20			ns	
Write Cycle Time	$t_{ m WC}$	120			ns	
Write Pulse Width	t_{WP}	100			ns	3
Write Recovery	$t_{ m WR}$	20			ns	10
Data Setup Time	$t_{ m DS}$	45			ns	4
Data Hold Time	t_{DH}	0			ns	4
CE Pulse Width	t_{CW}	105			ns	
RESET Pulse Width	t_{RST}	120			ns	

POWER-DOWN/POWER-UP TIMING	Over the operating range (3.3V)
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			<u> </u>			
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
$\overline{\text{CE}}$ at V_{IH} before Power-Down	t_{PD}	0			μs	
V_{CC} Slew from $V_{PF(MAX)}$ to	t_{F}	300			μs	
$V_{PF(MIN)}(\overline{CE} \text{ at } V_{IH})$						
V _{CC} Slew from V _{PF(MAX)} to	t_R	0			μs	
$V_{PF(MIN)}(\overline{CE} \text{ at } V_{IH})$						
\overline{CE} at V_{IH} after Power-Up	t_{REC}	1.5		2.5	ms	

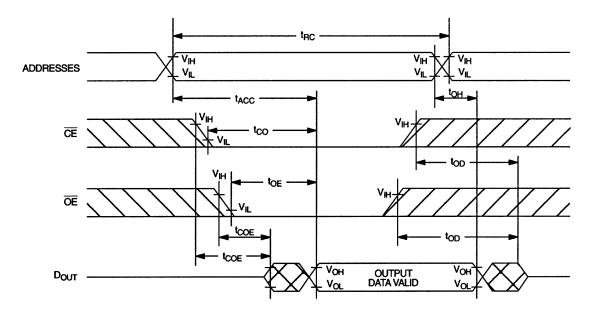
 $(t_A = 25^{\circ}C)$

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Expected Data Retention Time	t_{DR}	10			years	9

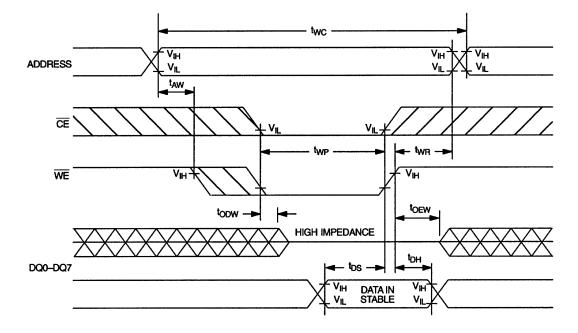
WARNING:

Under no circumstances are negative undershoots, of any amplitude, allowed when device is in battery backup mode.

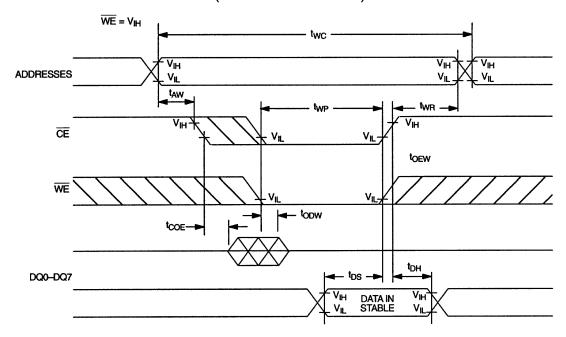
MEMORY READ CYCLE (NOTE 1)



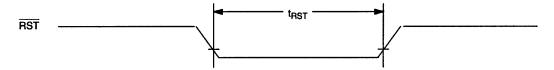
MEMORY WRITE CYCLE 1 (NOTES 2, 6, AND 7)



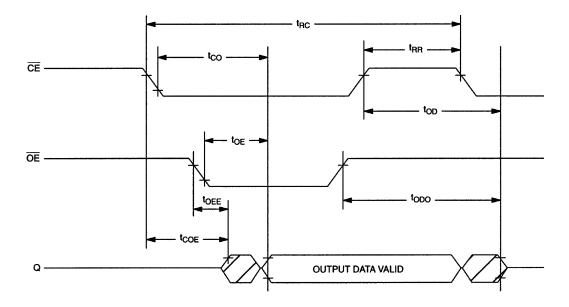
MEMORY WRITE CYCLE 2 (NOTES 2 AND 8)



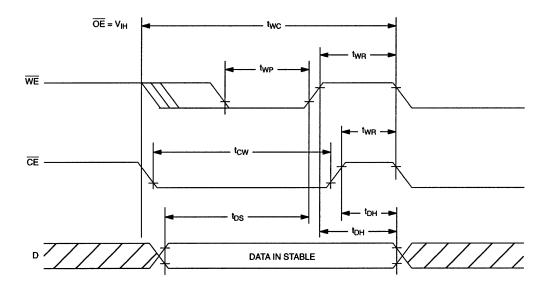
RESET FOR PHANTOM CLOCK



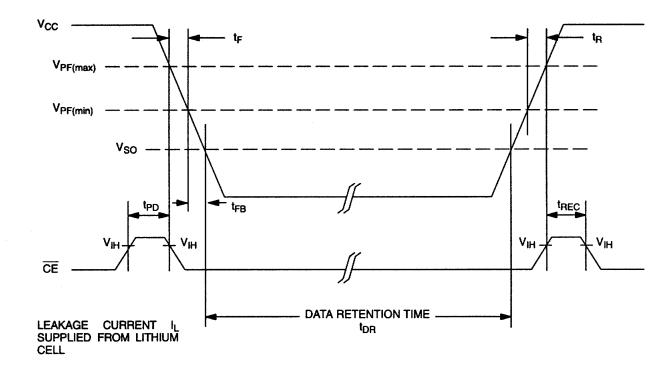
READ CYCLE TO PHANTOM CLOCK



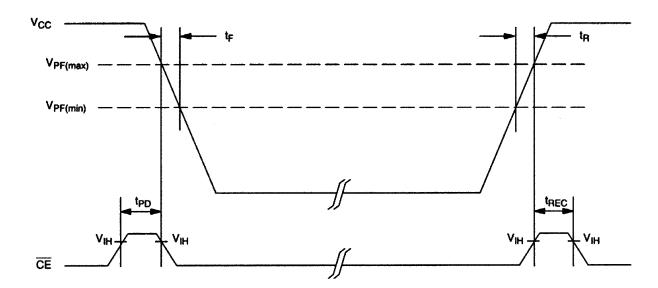
WRITE CYCLE TO PHANTOM CLOCK



POWER-DOWN/POWER-UP CONDITION (5 VOLT DEVICE)



POWER-DOWN/POWER-UP CONDITION (3.3 VOLT DEVICE)



AC TEST CONDITIONS

Output Load: 50 pF + 1TTL Gate Timing Measurement Reference Levels

Input: 1.5V

Input Pulse Levels: 0–3V Output: 1.5V Input Pulse Rise and Fall Times: 5 ns

NOTES:

1. WE is high for a read cycle.

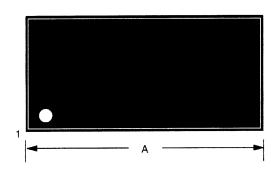
- 2. $\overline{OE} = V_{IH}$ or V_{IL} . If $\overline{OE} = V_{IH}$ during write cycle, the output buffers remain in a high impedance state.
- 3. t_{WP} is specified as the logical AND of \overline{CE} and \overline{WE} . t_{WP} is measured from the latter of \overline{CE} or \overline{WE} going low to the earlier of \overline{CE} or \overline{WE} going high.
- 4. t_{DH} , t_{DS} are measured from the earlier of CE or WE going high.
- 5. These parameters are sampled with a 50 pF load and are not 100% tested.
- 6. If the \overline{CE} low transition occurs simultaneously with or later than the \overline{WE} low transition in Write Cycle 1, the output buffers remain in a high impedance state during this period.
- 7. If the $\overline{\text{CE}}$ high transition occurs prior to or simultaneously with the $\overline{\text{WE}}$ high transition, the output buffers remain in a high impedance state during this period.
- 8. If $\overline{\text{WE}}$ is low or the $\overline{\text{WE}}$ low transition occurs prior to or simultaneously with the $\overline{\text{CE}}$ low transition, the output buffers remain in a high impedance state during this period.
- 9. The expected t_{DR} is defined as cumulative time in the absence of V_{CC} with the clock oscillator running.
- 10. t_{WR} is a function of the latter occurring edge of \overline{WE} or \overline{CE} .
- 11. Voltages are referencd to ground.
- 12. RST (Pin 1) has an internal pull-up resistor.
- 13. Real-Time Clock Modules can be successfully processed through conventional wave-soldering techniques as long as temperature exposure to the lithium energy source contained within does not exceed +85°C. Post solder cleaning with water washing techniques is acceptable, provided that ultrasonic vibration is not used.

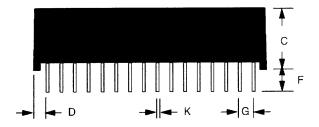
In addition, for the PowerCap:

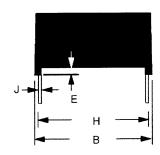
- a. Dallas Semiconductor recommends that PowerCap Module bases experience one pass through solder reflow oriented with the label side up ("live bug").
- b. Hand Soldering and touch—up: Do not touch or apply the soldering iron to leads for more than 3 (three) seconds.

To solder, apply flux to the pad, heat the lead frame pad and apply solder. To remove the part, apply flux, heat the lead frame pad until the solder reflow and use a solder wick to remove solder.

DS1244 256k NV SRAM WITH PHANTOM CLOCK



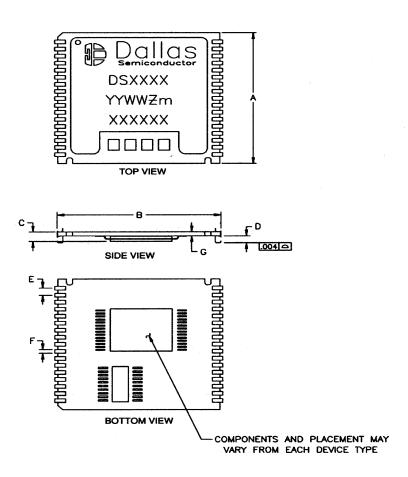




PKG	28-PIN		
DIM	MIN	MAX	
A IN.	1.520	1.540	
MM	38.61	39.12	
B IN.	0.720	0.740	
MM	18.29	18.80	
C IN.	0.395	0.415	
MM	10.03	10.54	
D IN.	0.100	0.130	
MM	2.54	3.30	
E IN.	0.017	0.030	
MM	0.43	0.76	
F IN.	0.120	0.160	
MM	3.05	4.06	
G IN.	0.090	0.110	
MM	2.29	2.79	
H IN.	0.590	0.630	
MM	14.99	16.00	
J IN.	0.008	0.012	
MM	0.20	0.30	
K IN.	0.015	0.021	
MM	0.38	0.53	

DS1244P

PKG	INCHES			
DIM	MIN	NOM	MAX	
A	0.920	0.925	0.930	
В	0.980	0.985	0.990	
C	-	-	0.080	
D	0.052	0.055	0.058	
Е	0.048	0.050	0.052	
F	0.015	0.020	0.025	
G	0.025	0.027	0.030	



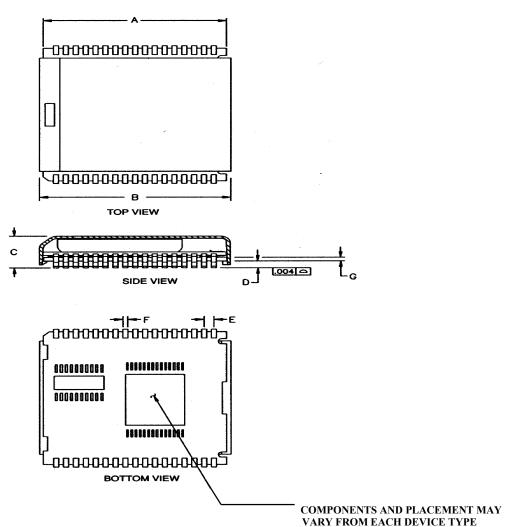
NOTE:

Dallas Semiconductor recommends that PowerCap Module bases experience one pass through solder reflow oriented with the label side up ("live – bug").

Hand Soldering and touch—up: Do not touch or apply the soldering iron to leads for more than 3 (three) seconds. To solder, apply flux to the pad, heat the lead frame pad and apply solder. To remove the part, apply flux, heat the lead frame pad until the solder reflows and use a solder wick to remove solder.

DS1244P WITH DS9034PCX ATTACHED

PKG	INCHES			
DIM	MIN	NOM	MAX	
A	0.920	0.925	0.930	
В	0.955	0.960	0.965	
С	0.240	0.245	0.250	
D	0.052	0.055	0.058	
Е	0.048	0.050	0.052	
F	0.015	0.020	0.025	
G	0.020	0.025	0.030	



RECOMMENDED POWERCAP MODULE LAND PATTERN

PKG	INCHES			
DIM	MIN	NOM	MAX	
A	-	1.050	-	
В	-	0.826	-	
C	-	0.050	-	
D	-	0.030	-	
Е	-	0.112	-	

